GH5CD05B3D **Hologram Lasers**

GH5CD05B3D

Features

- (1) Wide operating temperature for use in automotive
- (2) 3V operation (3 to 5), it is connectable with a chip set of
- (3) For ×8 speed CD drives, with built-in OPIC* (response speed: MIN. 12MHz) (Both for CD car navigation systems and CD players)
- (4) Thin (4.8mm thickness) and compact package enables thin and compact pick-up design.
- (5) With built-in beam splitter and diffraction grating *OPIC: (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and a signal-processing circuit integrated onto a single chip.

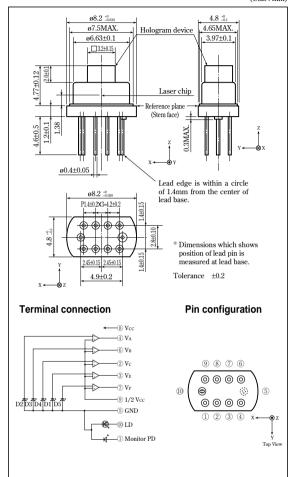
Applications

- CD players for automotive use
- (2) CD car navigation systems

Hologram Laser for Automotive CD Drive

Outline Dimensions

(Unit:mm)



Abcolute Maximum Detings

	ADSOIDLE WAXIIIUIII Natiliys					
	Parame	eter	Symbol	Rating	Unit	
*1	Optical power output	Рн	4.3	mW		
	Daviana valtana	Laser	V_R	2	V	
	Reverse voltage	Monitor photodiode	VR	30	V	
	OPIC supply voltag	Vcc	6	V		
*2	Operating temperat	Topr	-20 to +80	°C		
*2	Storage temperatur	Tstg	-40 to +85	°C		
#3	Soldering temperat	Tsold	260	°C		

^{*1} Output power from hologram laser, CW (Continuous Wave) drive

SHARP

(To-25°C)

Case temperature

At the position of 1.6mm from the lead base (Within 5s)

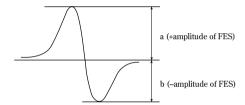
■ Electro-optical Characteristics

(Vcc=5V, Vs=1/2 Vcc, Tc=25°C)

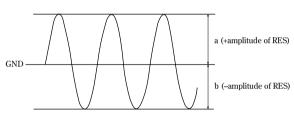
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*1 Focal offset	DEF	V _{RF} =1.1V	-0.7	-	+0.7	μm
*2 Focal error symmetry	Bres	V _{RF} =1.1V	-25	-	+25	%
*3 Radial error balance	Bres	P _H =3.0mW	-25	-	+25	%
**4 RF output amplitude	Vrf	P _H =3.0mW	0.90	1.70	-	V
*5 FES output amplitude	VFES	V _{RF} =1.1V	0.46	0.70	0.94	V
*6 RES output amplitude	Vres	V _{RF} =1.1V	0.25	0.36	0.49	V
Threshold current	Ith	_	-	25	39	mA
Operating current	Iop	P _H =3.0mW	-	36	50	mA
Operating voltage	Vop	P _H =3.0mW	-	1.75	2.2	V
Wavelength	λ_{p}	P _H =3.0mW	770	780	795	nm
Output current	Im	P _H =3.0mW, V _R =15V	(0.12)	0.55	1.00	mA
Differential efficiency	ηd	2.0mW I(3.0mW)-I(1.0mW)	0.17	0.27	0.55	mW/mA

 $^{^{*1}}$ Distance between FES=0 and jitter minimum point At the condition of FES sensitivity = 20%/1 μm

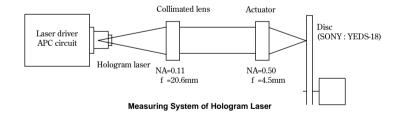
^{*2 (}a-b) / (a+b)







- **4 Amplitude of Va+VB+2Vc (focal servo ON, radial servo ON)
- *5 VA-VB (Focal vibration)
- *6 VE-VF (focal servo ON, radial servo OFF)



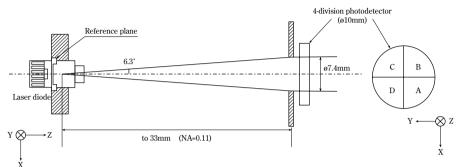
Hologram Lasers GH5CD05B3D

■ Electro-optical Characteristics of Laser Diode (Design Standard*)

(Tc=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Emission	*1 Symmetry	Parallel	S//	Do 2mW Into NA 0.11	-25	-	+25	%
characteristics	Symmeny	Perpendicular	S⊥	Po=3mW, Into NA=0.11	-15	-	+15	%
·		Δx		-80	-	+80	μm	
Misalignment pos	Misalignment position		Δy	_	-80	-	+80	μm
		Δz		-80	-	+80	μm	
Interference pattern intensity		α	Po=3mW	-	-	0.99	-	

^{*1} Measuring method of radiation symmetry



Parameter	Definition
S//	$\frac{(P_{\rm B} + P_{\rm C}) - (P_{\rm A} + P_{\rm D})}{P_{\rm A} + P_{\rm B} + P_{\rm C} + P_{\rm D}}$
s⊥	$\frac{(P_A + P_B) - (P_C + P_D)}{P_A + P_B + P_C + P_D}$

Px: Output of light detector X

■ Electrical Characteristics of Monitor Photodiode (Design Standard*)

(Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*2 Sensitivity	S		-	0.20	-	mA/mW
Dark current	ID	V _R =15V	-	-	150	nA
Terminal capacitance	Ct		1	3.5	-	pF

^{*2} For hologram output power

■ Electro-optical Characteristics of OPIC for Signal Detection (Design Standard*)

(Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	*3 Segment
Supply voltage	Vcc	-	2.8	3.0	5.5	V	-
Supply current	Icc	Vcc=3V	1.8	4.2	6.7	mA	-
**4 Output offset voltage	Vod		-11	0	+11	mV	Va, Vb, Vc
Output onset voltage		Vcc=3V	-13	0	+13	mV	Ve, Ve
Offt1t 1:ff	Vod	No light	-11	0	+11	mV	V _A -V _B
Offset voltage difference			-13	0	+13	mV	V _E -V _F
D	fcF	**5 Vcc=3V, -3dB	12	18	-	MHz	Va, Vb, Vc
Response frequency	fcr	Rl=10kΩ, Cl=10pF	1.2	1.8	-	MHz	Ve, Ve

^{*3} Applicable divisions correspond to output terminals.

D1	
D2	D4
D3	D4
D5	

Segment No.	Output
D 1	V _E
D 2	VA
D 3	V _B
D 4	Vc
D.F.	W _n

^{*} These parameters are not guaranteed performance, but general specifications of each optical element which makes up a hologram laser.

^{*4} Difference from Vcc/2

^{*5} Output amplitude=0dB (input signal 100kHz) BW=10kHz

[•] Please refer to the chapter "Handling Precautions"

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